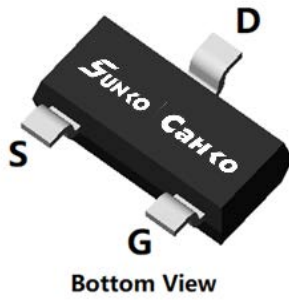
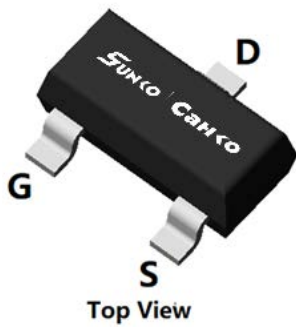
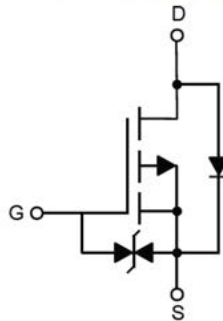


P-Channel Enhancement Mode Field Effect Transistor



SOT-23



Product Summary

- V_{DS} -30V
- I_D -2.7A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) $<85m\Omega$
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) $<125m\Omega$
- ESD Protected Up to 2KV (HBM)

General Description

- High Speed switching
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL94 V-0 Flammability Rating
- Halogen Free

Applications

- PWM applications
- Power management
- Load switch

Limiting Values

Parameter	Conditions	Symbol	Min	Max	Unit
Drain-source Voltage	$T_J \geq 25^\circ C; T_J \leq 150^\circ C$	V_{DS}	-	-30	V
Gate-source Voltage	$T_J \leq 150^\circ C; DC$	V_{GS}	-20	20	
Continuous Drain Current (Note 1,2)	Steady-State	I_D	-	-2.7	A
	$T_A=25^\circ C, V_{GS}=-10V$		-	-1.9	
Pulsed Drain Current	$T_A=25^\circ C, t_p \leq 10\mu s$	I_{DM}	-	-22	
Maximum Body-Diode Continuous Current	$T_A=25^\circ C$	I_S	-	-1.3	
Total Power Dissipation (Note 1,2)	Steady-State	P_D	-	0.95	W
	$T_A=100^\circ C$		-	0.38	
Junction and Storage Temperature Range		T_J, T_{STG}	-55	150	$^\circ C$

Thermal Resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	$R_{\theta JA}$	-	131	$^\circ C/W$

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SCL085P03AK	F2	08503.	3000	30000	120000	7" reel

■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A, T_J=25^{\circ}C$	-30	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V, T_J=25^{\circ}C$	-	-	-1	μA
		$V_{DS}=-30V, V_{GS}=0V, T_J=150^{\circ}C$	-	-	-100	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V, T_J=25^{\circ}C$	-	-	± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A, T_J=25^{\circ}C$	-1.0	-1.5	-2.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-1.8A, T_J=25^{\circ}C$	-	66	85	$m\Omega$
		$V_{GS}=-4.5V, I_D=-0.9A, T_J=25^{\circ}C$	-	96	125	$m\Omega$
Diode Forward Voltage	V_{SD}	$I_S=-1.8A, V_{GS}=0V, T_J=25^{\circ}C$	-	-0.86	-1.2	V
Gate Resistance	R_G	$f=1MHz, T_J=25^{\circ}C$	-	19	-	Ω
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V, f=1MHz, T_J=25^{\circ}C$	-	213	-	pF
Output Capacitance	C_{oss}		-	40	-	
Reverse Transfer Capacitance	C_{rss}		-	29	-	
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=-10V, V_{DS}=-15V, I_D=-1.8A, T_J=25^{\circ}C$	-	5.5	-	nC
Gate-Source Charge	Q_{gs}		-	0.25	-	
Gate-Drain Charge	Q_{gd}		-	0.85	-	
Reverse Recovery Charge	Q_{rr}	$I_F=-1.8A, di/dt=100A/\mu s, V_{GS}=0V, V_R=-15V, T_J=25^{\circ}C$	-	18	-	nC
Reverse Recovery Time	t_{rr}		-	45	-	ns
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-10V, V_{DS}=-15V, I_D=-1.8A, R_L=8.3\Omega, R_{GEN}=3\Omega, T_J=25^{\circ}C$	-	4.5	-	ns
Turn-on Rise Time	t_r		-	2.3	-	
Turn-off Delay Time	$t_{D(off)}$		-	16	-	
Turn-off Fall Time	t_f		-	11	-	

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of $R_{\theta JA}$ is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with $T_A=25^{\circ}C$. The maximum allowed junction temperature of $150^{\circ}C$. The value in any given application depends on the user's specific board design.
- Thermal resistance from junction to soldering point (on the exposed drain pad)

■ Typical Electrical and Thermal Characteristics Diagrams

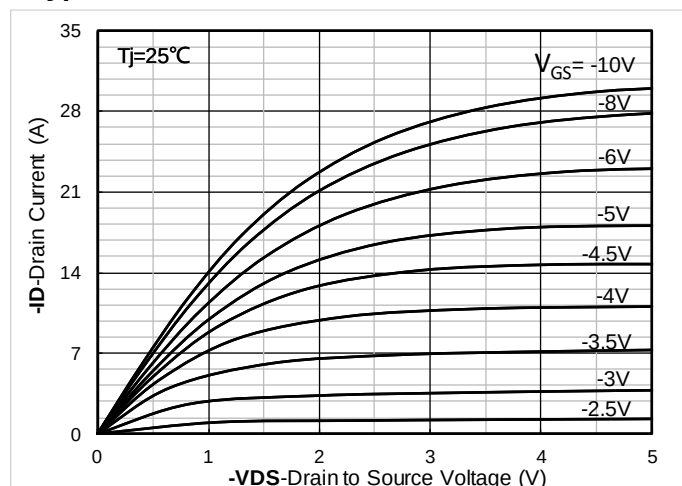


Figure 1. Output Characteristics; typical values

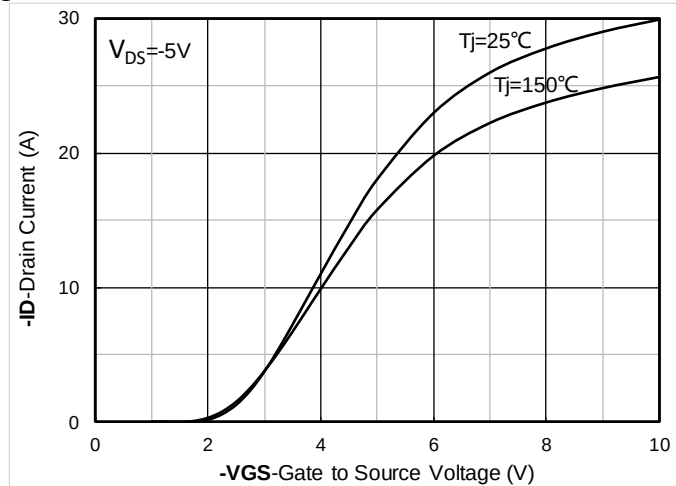


Figure 2. Transfer Characteristics; typical values

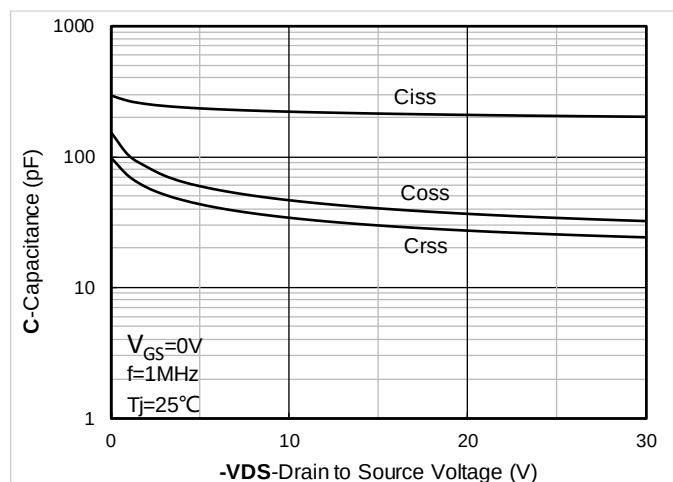


Figure 3. Capacitance Characteristics; typical values

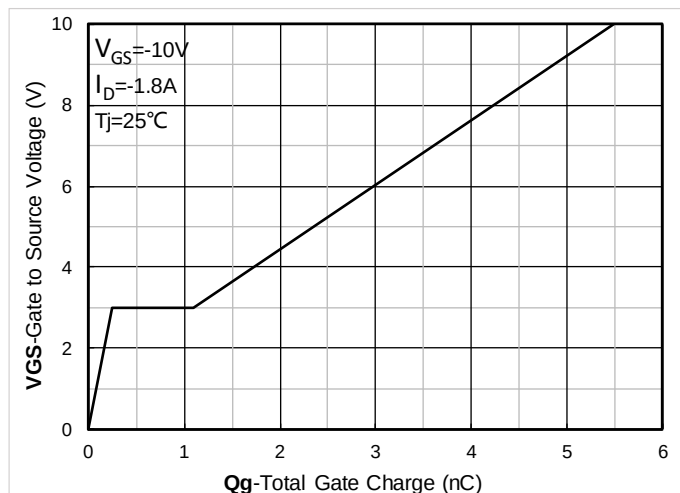


Figure 4. Gate Charge; typical values

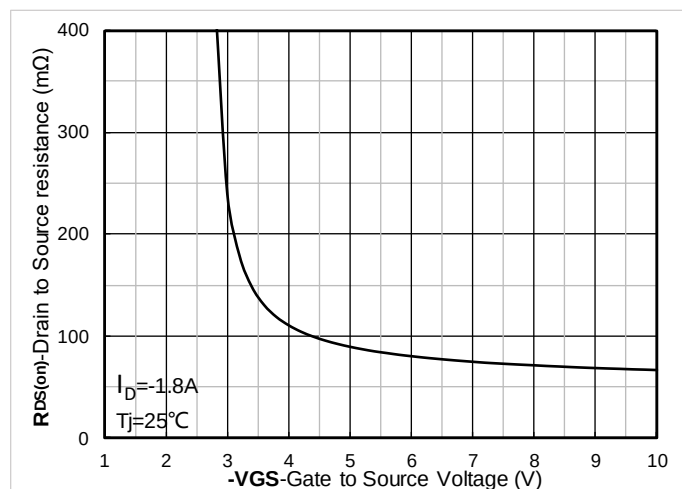


Figure 5. On-Resistance vs Gate to Source Voltage; typical values

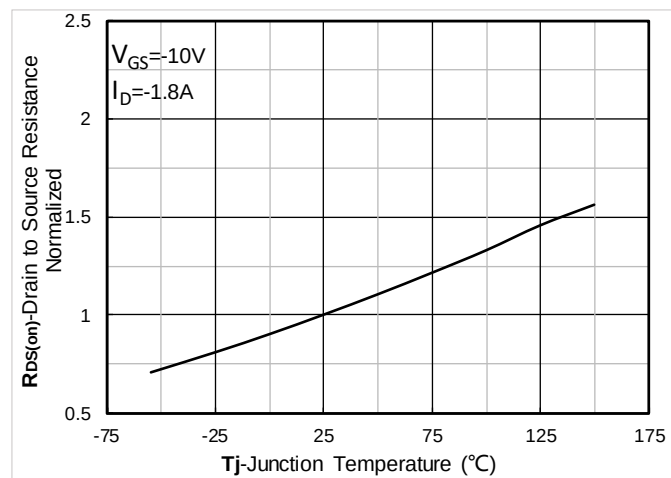


Figure 6. Normalized On-Resistance

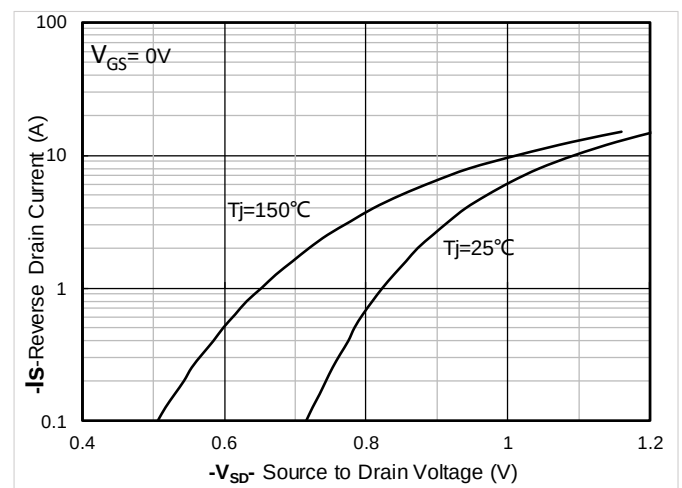
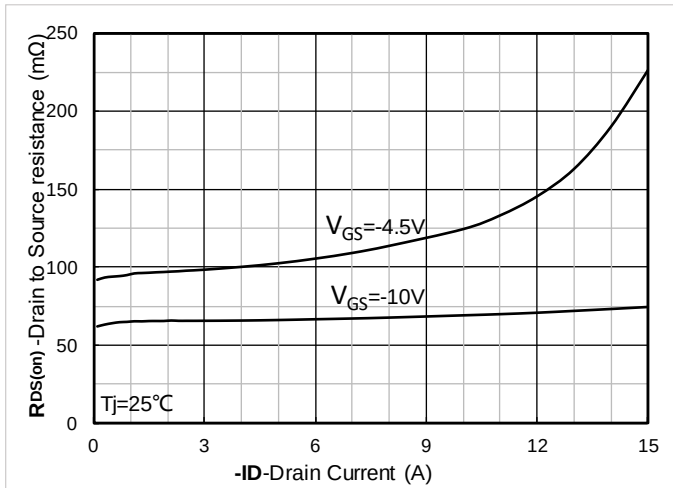


Figure 7. $R_{DS(on)}$ VS Drain Current; typical values

Figure 8. Forward characteristics of reverse diode; typical values

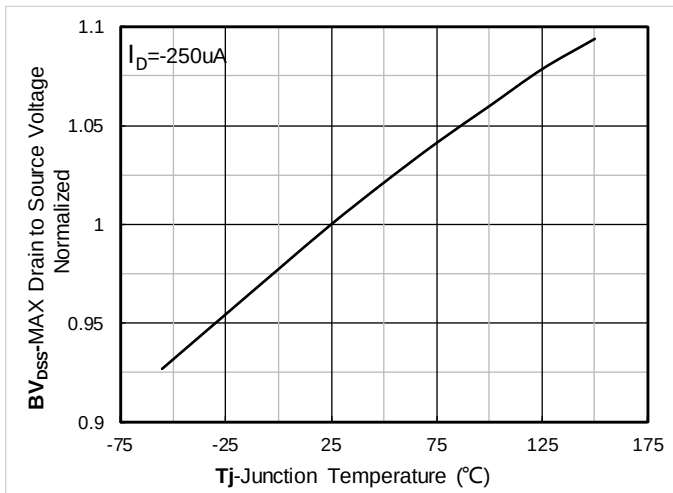


Figure 9. Normalized breakdown voltage

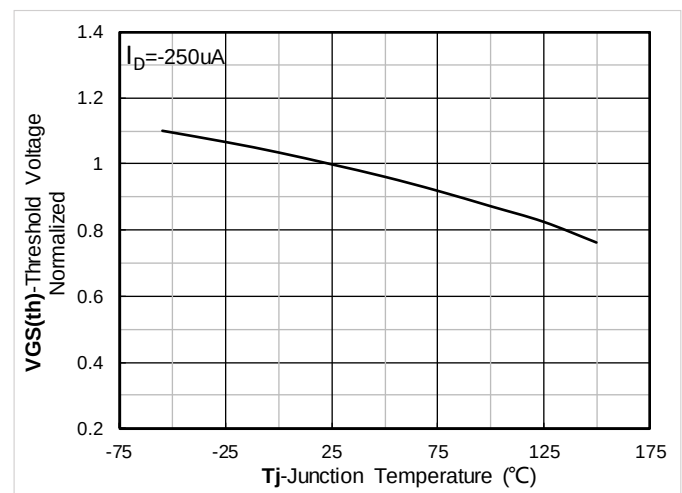


Figure 10. Normalized Threshold voltage

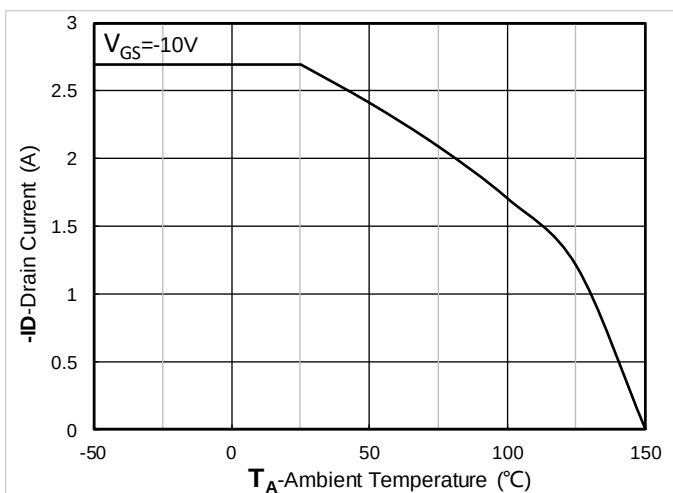


Figure 11. Current dissipation

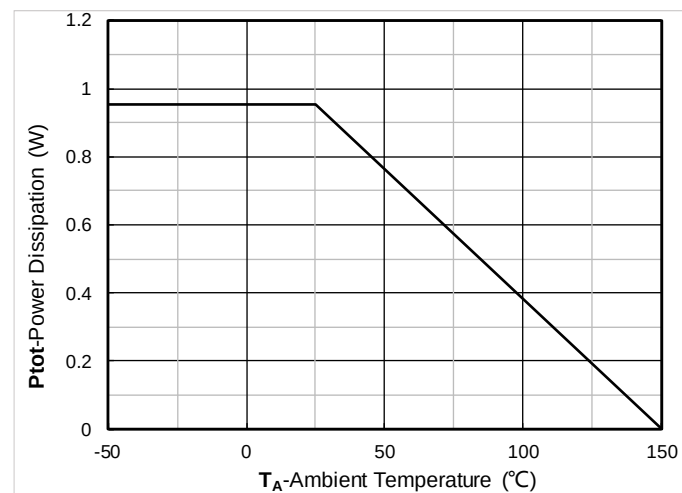


Figure 12. Power dissipation

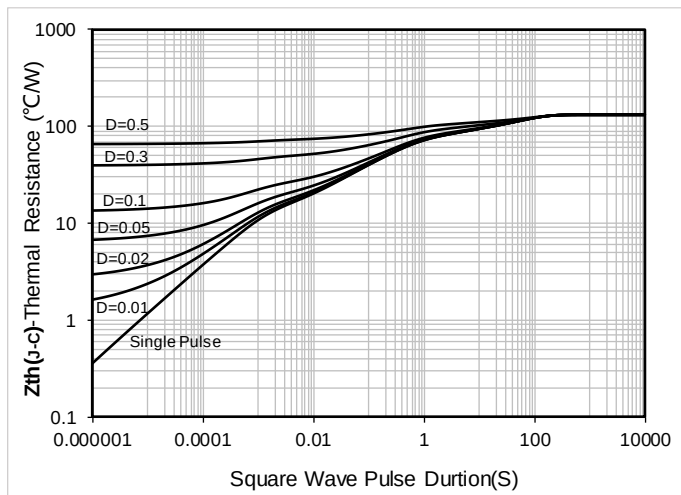


Figure 13. Maximum Transient Thermal Impedance

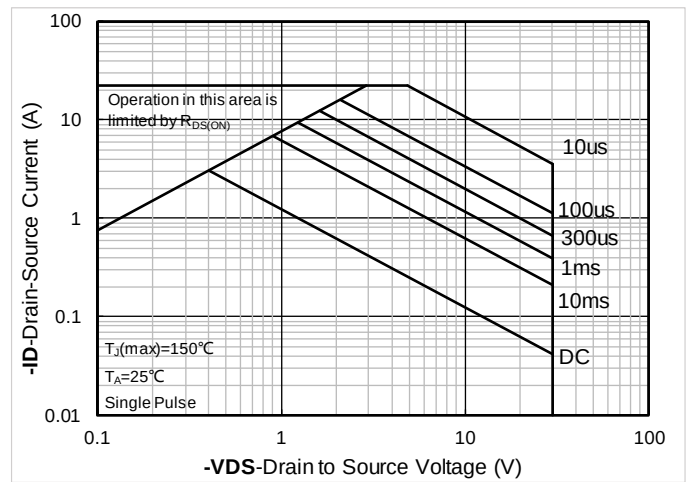
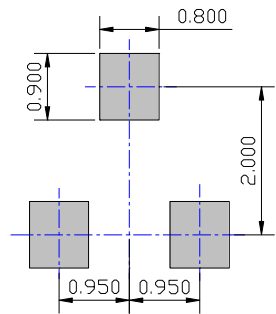
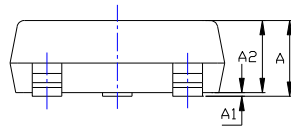
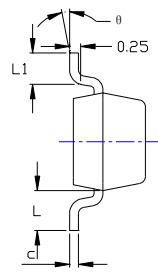
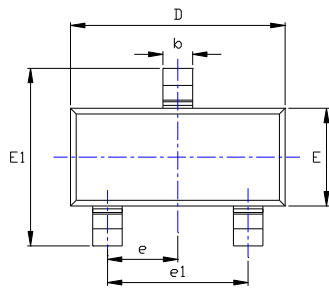


Figure 14. Safe Operation Area

■ SOT-23 Package information



UNIT: mm

SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037 TYP		0.950 TYP	
e1	0.071	0.079	1.800	2.000
L	0.022 REF		0.550 REF	
L1	0.012	0.020	0.300	0.500
θ	0°	8°	0°	8°

NOTE:
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
 3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

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